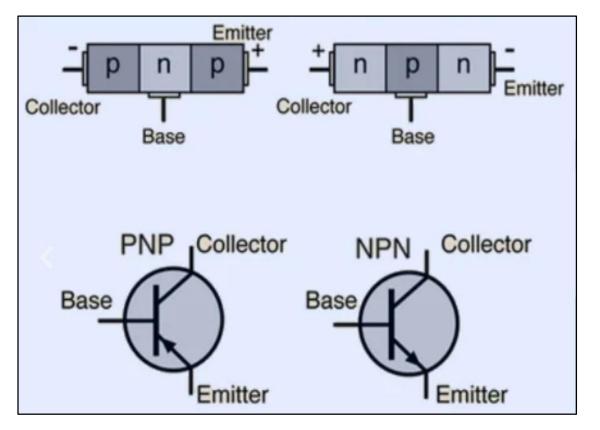
Lecture 3B: BJT Circuits

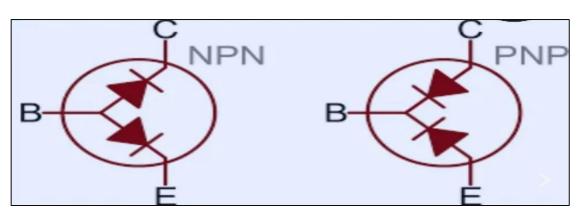
EE 103

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Bipolar Junction Transistor (BJT)





Parameter	ВЈТ
Types	Based on the construction, BJTs are classified into two types: NPN and PNP
Terminals	BJT has three terminals viz. emitter, base and collector.
Controlling quantity	BJT is a current controlled device Base current (I_B) controls the Collector Current (I_C)
Applications	BJT is used in Following applications Amplifiers Oscillators Switches Buffers

Modes of Operation

- BJT has Three terminals, Two junctions:
 - Base-Emitter Junction and Base Collector Junction
- Base-Emitter is the main controlling junction
- Three main modes of operation:
 - Cut-off: Both Base-Emitter and Base-Collector junctions reverse-biased
 - Active: Base-Emitter junction is forward-biased, Base-Collector junction reverse biased.
 - Saturation: Both Base-Emitter and Base-Collector junctions are forwardbiased

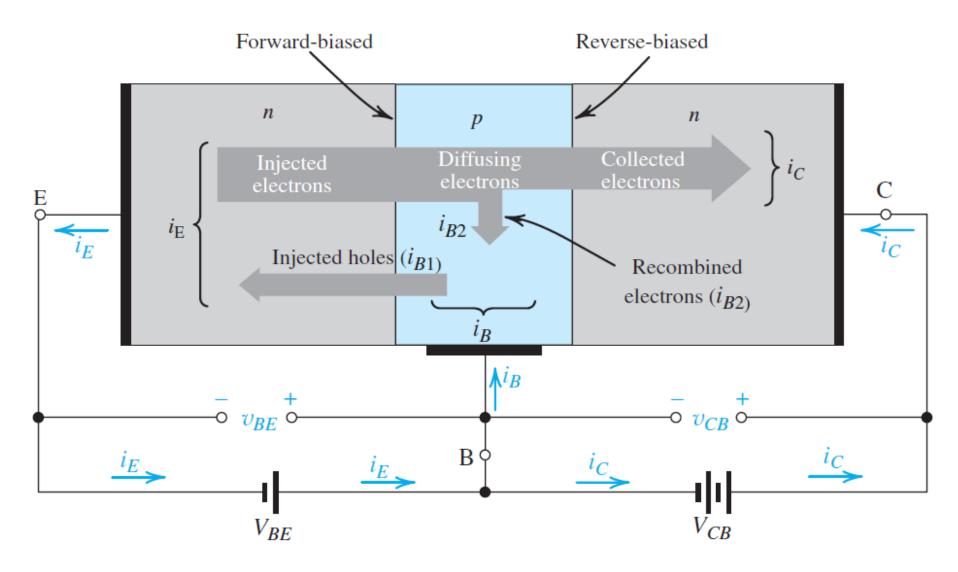


Figure 6.3 Current flow in an *npn* transistor biased to operate in the active mode. (Reverse current components due to drift of thermally generated minority carriers are not shown.)

Basic Equations

- $I_E = I_B + I_C (KCL) always true$
- $\beta = I_C/I_B$ (Current gain in the Common-Emitter mode)
 - β >> 1
 - Common Emitter: Input applied between Base and Emitter, Output between Collector and Emitter. Emitter is common to both input and output.
- $\alpha = I_C/I_E$ (Current gain in the Common-Base mode)
 - α < 1
 - Common Base: Input applied between Emitter and Base, Output between Collector and Base. Base is common to both input and output.
- $\beta = \alpha/(1-\alpha)$; $\alpha = \beta/(\beta+1)$

BJT Inverter Circuit

BJT Inverter

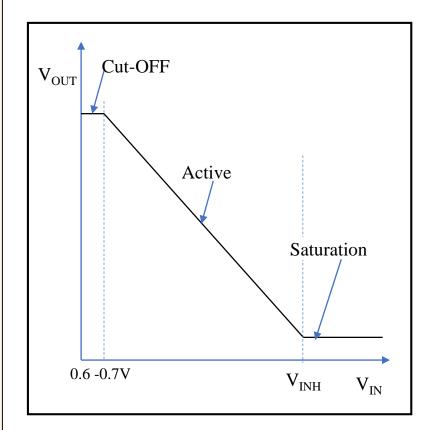
- Case-1 $V_{IN} < V_{BE}$ (Less than PN Junction Conduction Voltage) $I_B = 0, I_C = 0. \rightarrow V_{out} = V_{CE} = V_{CC}$ (BJT is said to be Cut-off)
- Case-2 $V_{IN} > V_{BE}$ BJT Conducts, with $I_B > 0$

$$\begin{split} I_B &= (V_{IN}\text{-}V_{BE}) / \ R_B \qquad \text{and} \qquad I_C = \beta \ I_B \Rightarrow V_{OUT} = V_{CE} = V_{CC}\text{-}\ I_C R_C \\ V_{CEmin} &= V_{CE\ Sat} = 0.2\ V \qquad \qquad I_{CMax} = (V_{CC}\text{-}V_{CESat}) / \ R_C = \beta \ I_{BSat} \\ \text{At that point } V_{BE} &= 0.7\ V \quad \text{and} \quad \text{Corresponding } V_{INH} = I_{BSat}\ R_B + V_{BE} \end{split}$$

(Active/ Linear Region)

• Case-3 $V_{IN}>V_{INH}$ $I_B=(V_{IN}\text{-}V_{BESat})/\ R_B \qquad \text{and} \quad I_C=I_{CMax} \qquad \text{But} \quad I_B\ \beta>I_{CMax}$ (BJT is said to be in Saturation)





BJT DC Circuits